



10A, 100V - 200V Schottky Barrier Rectifier

FEATURES

- AEC-Q101 qualified available
- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

- Case: ITO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
 Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.70g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _F	10	Α		
V_{RRM}	100 - 200	V		
I _{FSM}	120	Α		
T _{J MAX}	175	°C		
Package	ITO-220AB			
Configuration	Dual dies			

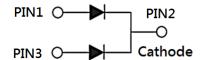








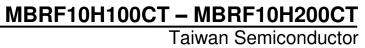
ITO-220AB



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	MBRF	MBRF	MBRF	UNIT	
		10H100CT	10H150CT	10H200CT	ST	
Marking code on the device		MBRF	MBRF	MBRF		
		10H100CT	10H150CT	10H200CT		
Repetitive peak reverse voltage	V_{RRM}	100	150	200	V	
Reverse voltage, total rms value	V _{R(RMS)}	70	105	140	V	
Forward current	I _F	10			Α	
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	120			Α	
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}	1.0 0.5		0.5	Α	
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	10			Α	
Critical rate of rise of off-state voltage	dv/dt	10,000		V/μs		
Junction temperature	TJ	-55 to +175		°C		
Storage temperature	T _{STG}	-55 to +175			°C	

Notes:

1. $tp = 2.0\mu s$, 1.0KHz





THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP	UNIT		
Junction-to-case thermal resistance	R _{eJC}	3.5	°C/W		

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	MBRF10H100CT	I _F = 5A,T _J = 25°C	V _F	-	0.85	V
	MBRF10H150CT				0.88	V
	MBRF10H200CT			-	0.00	V
	MBRF10H100CT	I _F = 10A,T _J = 25°C		-	0.95	V
Forward voltage per diode ⁽¹⁾	MBRF10H150CT			-	0.97	V
	MBRF10H200CT					
	MBRF10H100CT	I _F = 5A,T _J = 125°C		-	0.75	V
	MBRF10H150CT					
	MBRF10H200CT					
	MBRF10H100CT			-	0.85	V
	MBRF10H150CT	$I_F = 10A, T_J = 125$ °C				
	MBRF10H200CT					
Reverse current @ rated V _R per diode ⁽²⁾		T _J = 25°C	I _R	-	5	μΑ
		T _J = 125°C	I _R	-	1	mA

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION					
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING			
MBRF10HxCT	ITO-220AB	50 / Tube			
MBRF10HxCTH	ITO-220AB	50 / Tube			

Notes:

- 1. "x" defines voltage from 100V(MBRF10H100CT) to 200V(MBRF10H200CT)
- 2. "H" means AEC-Q101 qualified

Fig.2 Typical Junction Capacitance



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

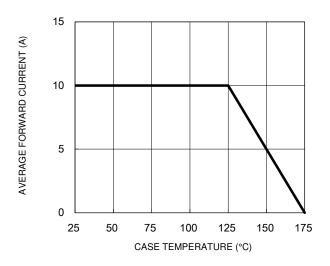


Fig.3 Typical Reverse Characteristics

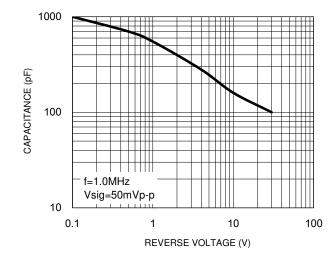
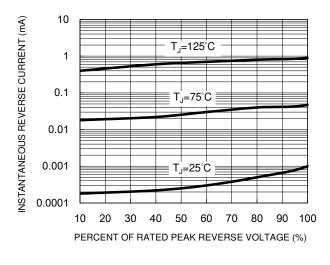


Fig.4 Typical Forward Characteristics



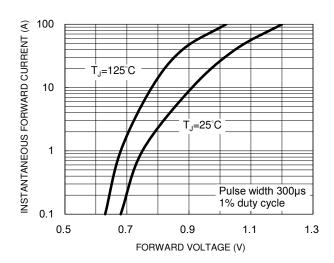
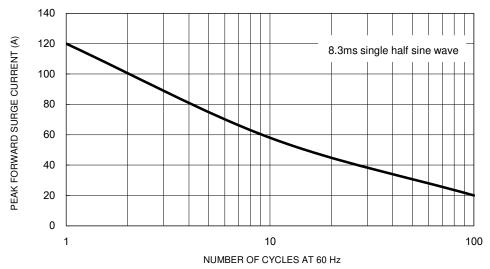


Fig.5 Maximum Non-Repetitive Forward Surge Current



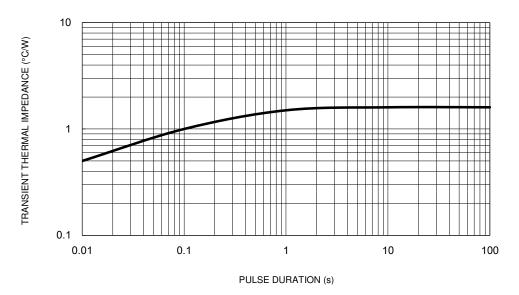
3

Taiwan Semiconductor

CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

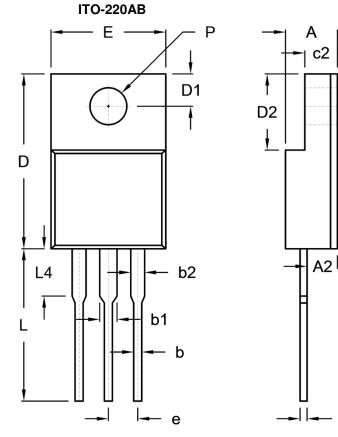
Fig.6 Typical Transient Thermal Impedance





Taiwan Semiconductor

PACKAGE OUTLINE DIMENSIONS



A2 -

DIM.	Unit	Unit (mm)		(inch)
DIIVI.	Min.	Max.	Min.	Max.
Α	4.30	4.70	0.169	0.185
A2	2.30	2.96	0.091	0.117
b	0.50	0.90	0.020	0.035
b1	-	1.80	-	0.071
b2	0.95	1.45	0.037	0.057
С	0.46	0.76	0.018	0.030
c2	2.50	3.16	0.098	0.124
D	14.80	15.50	0.583	0.610
D1	2.40	3.20	0.094	0.126
D2	6.30	6.90	0.248	0.272
E	9.60	10.30	0.378	0.406
е	2.41	2.67	0.095	0.105
L	12.60	13.80	0.496	0.543
L4	-	4.10	-	0.161
Р	3.00	3.40	0.118	0.134

MARKING DIAGRAM



P/N = Marking Code = Green Compound G

YWW = Date Code F = Factory Code



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.